

# MTRS1060, MTRS1070

## APPLICATIONS

- TAPE EDGE SENSOR
- PAPER POSITION SENSOR FOR PRINTERS AND FACSIMILES
- INDEX SENSOR FOR FLOPPY DISC DRIVE
- BAR CODE SCANNING

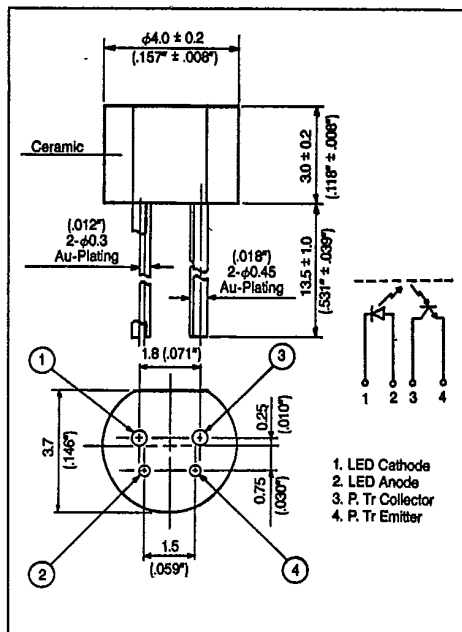
## FEATURES

- Small package size.
- Fast switching speed.
- High sensitivity.
- GaAlAs visible 660nm LED and silicon detector—MTRS1060.
- GaAlAs visible 700nm LED and silicon detector—MTRS1070.

## MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
A	Forward Current	$I_F$	50	mA
	Reverse Voltage	$V_R$	4	V
	Pulse Forward Current	$I_{FP}$	0.5*	A
	Power Dissipation	$P_D$	100	mW
B	Collector-Emitter Voltage	$V_{CEO}$	20	V
	Emitter-Collector Voltage	$V_{ECO}$	5	V
	Collector Current	$I_C$	50	mA
	Collector Power Dissipation	$P_C$	75	mW
C	Total Power Dissipation	$P_{TOT}$	100	mW
	Operating Temperature	$T_{opr}$	-20 ~ 90	°C
	Storage Temperature	$T_{stg}$	-30 ~ 100	°C

\* $P_W=10\mu s$ ,  $f=100\text{Hz}$



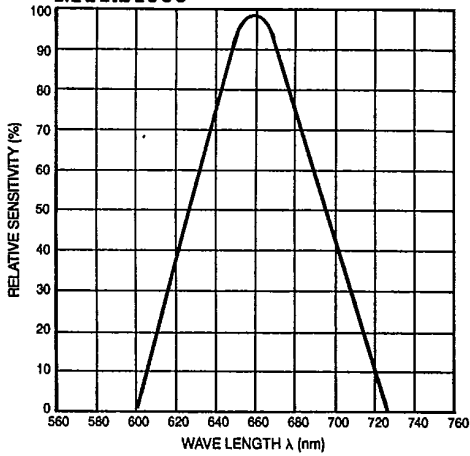
1. LED Cathode
2. LED Anode
3. P. Tr Collector
4. P. Tr Emitter

## OPTO-ELECTRICAL CHARACTERISTICS (Ta = 25°C)

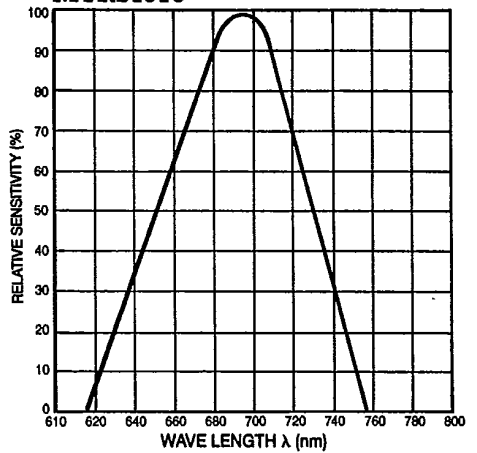
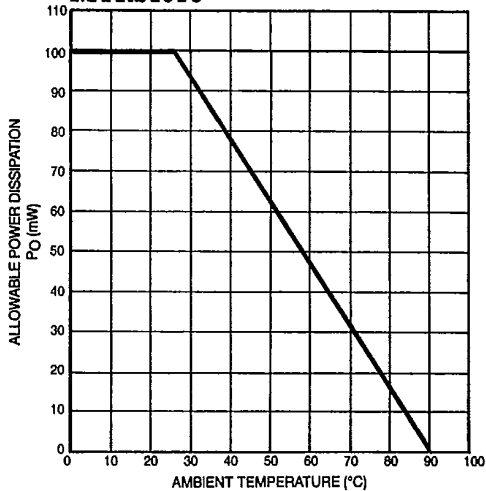
	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
A	Forward Voltage	$V_F$	$I_F=20\text{mA}$	—	1.7	2.1	V	
	Reverse Current	$I_R$	$V_R=4\text{V}$	—	—	10	$\mu\text{A}$	
	Peak Wave Length	MTRS1060 MTRS1070	$\lambda_p$	$I_F=20\text{mA}$	—	660 700	— —	nm
B	Collector Dark Current	$I_D (I_{CEO})$	$V_{CE}=10\text{V}$	—	—	100	nA	
C	Output Current	MTRS1060 MTRS1070	$I_O$	$I_F=20\text{mA}$ , $V_{CE}=2\text{V}$ , $d=1\text{mm}$	150 250	300 550	—	$\mu\text{A}$
	Cross Talk		$I_X$	$I_F=20\text{mA}$ , $V_{CE}=2\text{V}$	—	—	200	nA
	Switching Speed		$T_r$ $T_f$	$V_{CE}=5\text{V}$ $I_O=0.1\text{mA}$ $R_L=1\text{k}\Omega$	—	20 30	—	$\mu\text{A}$

A-EMITTER B-DETECTOR C-COUPLED

SPECTRAL RESPONSE

**MTRS1060**

SPECTRAL RESPONSE

**MTRS1070****MTRS1060**  
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